NSN 5962-01-261-4057

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View Online at https://aerobasegroup.com/nsn/5962-01-261-4057

Body Length:
1.111 inches
Body Width:
0.410 inches
Body Height:
0.210 inches
Maximum Power Dissipation Rating:
1.05 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and bipolar and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
20 input
Case Outline Source And Designator:
D-7 mil-m-38510
Current Rating Per Characteristic:
200.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Ram
Special Features:
Nuclear hardness critical items
Nuclear Hardness Critical Feature:
Hardened
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
22 printed circuit
Shelf Life:

N/a

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In	18	<i>(</i>)+	МА	261	ıre:

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Demilitarization:

No

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